## NSN 5961-00-982-6780

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-982-6780

**Inclosure Material:** 

Metal

**Overall Length:** 

1.005 inches

**Overall Diameter:** 

0.370 inches

**Mounting Facility Quantity:** 

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

450.0 breakdown voltage, collector-to-base, emitter open and 350.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

**Current Rating Per Characteristic:** 

1.00 amperes source cutoff current

**Power Rating Per Characteristic:** 

10.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

**Terminal Type And Quantity:** 

3 uninsulated wire lead

**Specification Data:** 

80131-release5399 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

---

**Demilitarization:** 

No

Fiig:

A110a0